

Nanoarray of Vivaldi Rectenna for Infrared-energy Harvesting

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Abstract – This article presents the design of an array of rectennas operating at 28.3 THz for infrared (IR) energy harvesting applications. The basic element of the array consists of a Vivaldi-dipole rectenna composed of two arms made with different conductors (gold and titanium). A metal-insulator-metal (MIM) tunnel diode is used to rectify the THz ac current. The proposed MIM diode consists of a very thin layer of Al₂O₃ sandwiched between the two metal electrodes. Arrays of two, three, and four rectennas are investigated. The improvement of the energy captured by coupling several elements in the same structure with a common gap is also investigated. This array architecture, without feeding network, may reduce the number of rectifying diodes and, therefore, decrease losses and increase the overall efficiency. Finally, it has been found that the four-elements rectenna array has a maximum electric field intensity of 62.4×10^4 V/m at 28.3 THz.

Index Terms – Energy harvesting, infrared (IR) energy, MIM diode, rectenna, THz, Vivaldi antenna array.

I. INTRODUCTION

Nowadays, wireless sensor networks are widely used in several applications related to industry, surveillance, monitoring of people and objects, home automation, scientific research, etc. This rapid expansion in using wireless systems is due, among other reasons, to the considerable developments and advances made in

microelectronics. These advances have enabled the integration of more and more functionalities in an increasingly smaller volume [1].

Unfortunately, research and development in energy storage technologies have not followed the same rapid trend. As a result, portable communications systems are finding themselves increasingly penalized regarding autonomy. To make these communication systems and objects more self-sufficient in energy and to increase the battery life, efficient electromagnetic energy harvesting systems are required. Collecting energy from the surrounding environment and converting it into usable electrical energy is a very interesting alternative to traditional usage of replaceable batteries [2]. These energy sources can be recovered from artificial devices or available natural sources [3–4].

The most direct and abundant source of energy comes from the Sun. Photovoltaic energy harvesting is a promising technology that converts solar energy in the visible spectrum into usable electrical energy [5], but this received energy from the sun is used in the visible region during the day only.

The energy released at night is in the infrared (IR) region within the spectral range 7-17 μm with a maximum power peak centred around the wavelength 10.6 μm (28.3 THz) [6–7]. In order to harvest and convert this available infrared energy, we need new devices to capture, convert, and store this energy. One solution that can exploit this abundant infrared energy from the

Earth's surface is to use energy harvesting based on nano-rectennas [4, 8]. A rectenna-based system, is composed of a receiving antenna with integrated rectifying diode [9–11].

Harvesting energy in the IR domain requires efficient design of the antenna and the rectifying diode, with deep understanding of the dielectric properties of materials in the optical band, especially in the infrared range [4, 12, 13].

The continuous technological evolution of electronic and optical materials at the nano-metric scale quickly leads to the design of devices which were not even possible a few years ago. Plasmonics is one of areas that benefit most from these advances [14–15]. Optical antennas are strongly analogous to their radio frequency counterparts, but there are crucial differences in their physical properties and behavior when scaled. Most of these differences arise because metals are not perfect conductors at optical frequencies, but rather are highly correlated plasmas described as a free electron gas. By definition, an optical antenna is a device that converts freely the radiation of propagating light into localized electromagnetic energy, and vice versa [16]. The fabrication of optical antenna structures is an emerging opportunity for new optoelectronic devices [17]. Optical antennas help to exceed the diffraction limit, making it possible to manipulate, control and visualize optical fields at the nano-metric scale, which offers a wide range of applications [18]. Among these are antenna probes for nano-imaging, non-linear signal conversion, and IR energy harvesting. These nano-antennas require specific studies to develop optical antennas.

Associated with the antenna, IR energy harvesting is based on the use of diodes as rectifiers. In the terahertz domain, the use of diodes and more particularly of Schottky and MIM diodes, is very useful at the level of the rectifier block. MIM diodes are very attractive and promising candidates for energy recovery in the infrared spectrum. The MIM diodes are a good candidate for infrared (IR) applications of the electromagnetic spectrum because of their high-speed characteristics and their compatibility with integrated circuits [4, 19].

Usually, a single rectenna element cannot supply sufficient captured wireless power. To increase the power recovered by the system, we must maximize the power captured. One way to achieve this is by increasing the surface area of the antennas; however, this will shift the omni-directional bandwidth toward the low frequencies. Another approach is to combine several elements in an array configuration. Several configurations of the second approach are already presented in literature, but they all suffer from some limitations: In [20], a rectenna array based on a 2-by-4 misaligned bowtie antenna is presented. Four spiral elements composed of three gold-based square spiral nano-antennas resonate near 13 μm

[21] with dimensions of 750×750 nm of each element. The system arrays have been coupled together in one structure with one common gap by using a feeding line. In both configurations cited in [20] and [21], the size of the feeding network is large compared to the array causing high ohmic losses, which reduce the intensity of the total collected electric field within the gap.

To increase further the captured electric field in arrays of nano-rectennas, authors in [22] optimized both the metal thickness of a bowtie nano array, (the optimal thickness was equal to 95 nm) in addition to the incident angle.

In this paper, we present a new design of nano-rectenna array, based on a Vivaldi rectenna operating at infrared wavelengths, with a maximum peak of collected power situated at 10.6 μm (28.3 THz). The structure is composed of an array of Vivaldi nano-rectennas placed in a configuration to create a hot spot in order to increase the intensity of the collected electric field within this localized zone. The main advantage of the proposed configuration is to remove the complex and lossy feeding network used in [22] and [23], in addition to the concentration of the electric field in one small region (hot spot) where the rectifying diode should be integrated. So, losses will be reduced, the captured electric field within the gap will be enhanced, and the total efficiency of the rectenna will be increased.

This article is organized as follows. Section II describes, respectively, the designs of one, two, three, and four antennas and their performances. The maximum fields captured for each case are presented. In section III, a similar study adds the rectifying MIM diode to form the rectennas. The design parameters of the Vivaldi nanoarrays are optimized to obtain maximum performance. The rectennas were simulated by using computer simulation technology (CST) software [24], where the dielectric properties of the metals (gold and titanium) are calculated based on the Drude-model.

II. VIVALDI NANO-ANTENNA

A. Vivaldi nano-antenna design

Currently, printed antennas are becoming more and more important because of the great variety of geometric shapes they can take, which make them applicable to different integration situations. This is a key property which explains the introduction of printed antennas in energy harvesting applications. This technology responds well to the needs of our application. Therefore, the design of the antennas must respond to compromises in terms of performance and complexity of implementation. The Vivaldi antenna is a simple planar antenna characterized by a wide band and linear polarization. The antenna element as shown in Fig. 1, presents an exponential curve profile in the XY plane. In The gap between the two arms of the antenna is defined by the following

function [25]:

$$g(x) = R(e^{Cx} - e^{-Cx}) + \frac{W_{min}}{2}, \quad (1)$$

where the coefficient C is the curvature parameter, W_{min} is the width of the gap line, and R is defined by:

$$R = \frac{\frac{W_{max}}{2} - \frac{W_{min}}{2}}{e^{CL} - e^{-C}}. \quad (2)$$

W_{max} is the opening width at the end of the arm and C is the length of the arm. The antenna configuration is symmetric around the x -axis.

The antenna element is composed of two arms: one in gold, with a dielectric constant ϵ_{rg} , loss tangent $\tan \delta_g$, and a thickness h_g ; and the other in titanium with a dielectric constant ϵ_{rti} , loss tangent $\tan \delta_{ti}$, and a thickness h_{ti} separated by a gap W_{min} . A detailed parametric study allowed us to obtain the optimal values of the different parameters of the final structure Vivaldi antennas are described in Table 1.

The dielectric properties of gold, used in the simulations are obtained by presenting the experimental data in a Drude model [4]:

$$\epsilon(\omega) = \epsilon_{\infty} - \frac{\omega_p^2}{\omega^2 - i\omega\omega_{\tau}}, \quad (3)$$

where ϵ_{∞} represents the contribution of electrons linked to the relative dielectric constant, ω_p is the frequency of the plasma (rapid oscillation of the electron density in conductive media such as metals), and ω_{τ} is the amortization frequency.

Table 1: Antenna dimensions and material properties

Parameters	Value (μm)	Parameters	Value (μm)
Wmax	40	ϵ_{rg} at 28.3 THz	6037.7
Wmin	0.05	$\tan \delta_g$ at 28.3 THz	0.4
L	2.7	ϵ_{rti} at 28.3 THz	430
h_{ti}	0.08	$\tan \delta_{ti}$ at 28.3 THz	0.98
hg	0.08	C	1.8

The advantage of this configuration is that it gives the designer the freedom to vary several antenna parameters in order to increase the electric field received. In addition, it produces a stronger electric field in its gap. Another advantage of Vivaldi's nano-antennas of this form is the ability to build an array by coupling many elements of the Vivaldi antenna in one configuration and combining the electric field of each element at the feed point of the network, where a rectifier can be integrated.

Light is an electromagnetic wave where the electric and magnetic fields are perpendicular to the direction of propagation (z -axis). To study the electric field at the

antenna gap, a linear polarized plane wave (along x -axis) with an electric field module equal to 1 V/m (see Fig. 1). The electric field component of the incident field is along the dipole axis y , and the direction of propagation is perpendicular to the dipole (along $-z$). The maximum value of the collected field is concentrated at the gap with a value 67.2 V/m at 28.3 THz, as shown in Fig. 2.

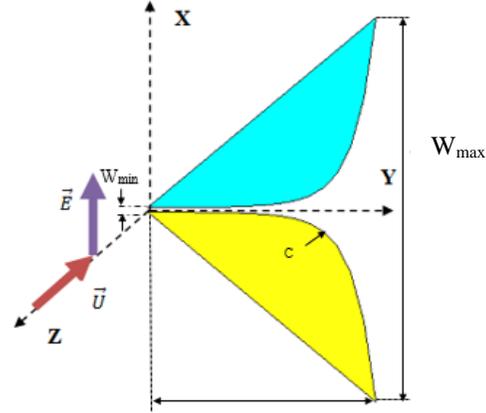


Fig. 1. Configuration parameters of the Vivaldi nano-antenna and direction of incident plane wave.

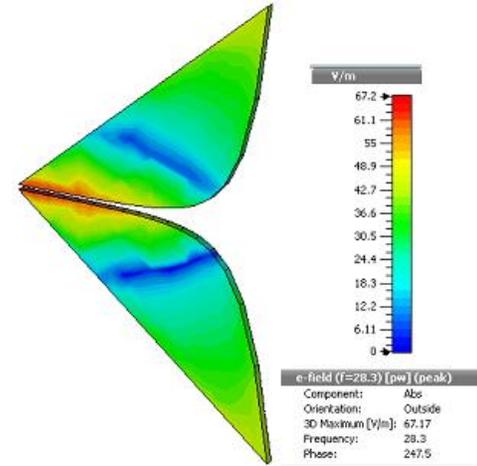


Fig. 2. Field distribution at 28.3 THz.

B. Vivaldi nano-antenna array

Vivaldi nano-antenna arrays have been used and studied due to their suitability for broadband operation and because they offer flexibility to optimize radiation properties by adjusting their configuration [22]. Figure 3 shows the configuration of the studied nano arrays. We started by designing a nanoarray of two elements to increase the captured electric field [26]. This network consists of two nano-antennas with a 30 nm gap to collect the electric field from the elements of the array, as shown in Fig. 3 (a). This simple design offers a higher electric field compared to a single element nano-antenna.

The dimensions of all nano-antennas in this array are the same as those in Fig. 1 with a slot of 30 nm separating the two identical nano-antennas. Figure 3 (b) shows three Vivaldi nano-antenna arrays based on gold and titanium, coupled together in a single network common gap. The nano-antenna arrays have been designed to resonate around 28.3 THz. Then, the four-element planar Vivaldi nanoarray, shown in Fig. 3 (c), has been designed to increase the electric field picked up for IR energy harvesting applications [22]. By coupling numerous elements in the geometry of an array, the far-field characteristics are improved and the output voltage is increased. In previous studies [8], methods of increasing the captured electric field by modifying the geometric parameters of the nano-antenna are presented. From the simulated results, the maximum electric field is produced by a 7 nm gap between the arms of the antenna. In addition, the captured electric field is improved if the size of the gap between the elements of the network at the supply point is reduced. Therefore, for the array of four elements, a Vivaldi nanoarray based on the optimized parameters is constructed to obtain maximum performance.

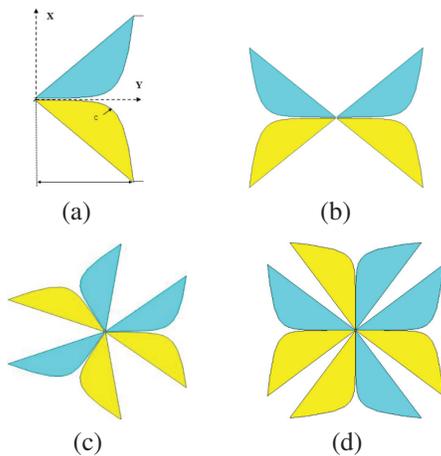


Fig. 3. Vivaldi nano-antenna: (a) single structure, (b) two elements array, (c) three elements array, and (d) four elements array.

C. Discussion

Figure 4 compares the solar energy harvesting capacities of the different arrays.

The intensity of single nano-antenna reaches a maximum value of 5×10^3 at 28.3 THz. The captured field is not sufficient with such a single-element antenna. However, this nano-antenna offers the possibility of capturing higher values by using it in a circular or hexagonal network by capturing the fields at the center of the array. In the case of a simple antenna, the received signal is often not sufficient to drive the rectifier. Thus, it is necessary to increase the gain of the receiving antenna by

increasing its electrical size. This can be accomplished by assembling the single element antennas in a circular array configuration. The total field captured by the array is determined by the addition of the fields captured by each individual element when the elements interfere constructively. The factors which control the overall performances of an array with identical elements are presented in [26]: the geometrical configuration, the space between the elements, the amplitude and the phase of excitation of the elements, and the contribution of the individual element. As we can see in Fig. 4, it is obvious that the four-antenna nanoarray reaches a maximum value of 10^5 at 28.3 THz, which is better for harvesting the electric field compared to other designs. It can be seen that the field captured at the center increases by increasing the number of nano-antennas integrated into the array.

This significant improvement in the collected field strength obtained with the nanoarray is mainly due to the increase in numbers of dipoles used. and therefore the increase in its electrical size, at the resonant frequency.

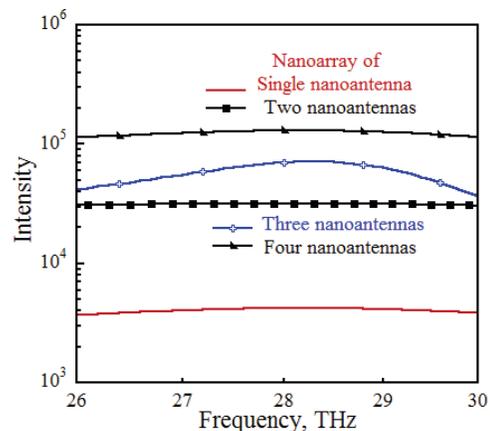


Fig. 4. The intensity variation captured vs. frequency for the different Vivaldi nanoarrays.

III. VIVALDI RECTENNA NANOARRAY

Electromagnetic energy harvesting systems require a wave receiving antenna connected to an RF/DC conversion system, thus forming a rectifier device or “Rectenna.” Currently, many challenges encountered in the design of rectennas for high performance are being studied. It leads to continuous progress in the understanding of light/matter interaction at optical frequencies. Recently, some researchers have shown a new low-cost nano-antenna manufacturing method [22].

Due to the geometric convenience of the dipole, the Vivaldi nano-antenna is chosen in this work to be the main resonator that integrates with the rectifier. However, the electric field picked up at the center of its gap is weak and needs to be further improved. That’s why an auxiliary resonant element is added to the structure, at the cen-

ter of this nano-antenna, in order to increase the captured field and improve its overall performance.

Regarding diodes, many promising new alternatives are being explored. For example, metal-insulator-metal (MIM) diodes, metal insulator-insulator-metal diodes (MIIM), traveling wave diodes, pointy diodes, and geometric diodes have been considered as potential candidates for these applications.

In this work, firstly, the dipole nano-antenna is simulated. The field picked up at the feed gap level is shown in Fig. 4. After that, the optimized nano-antenna is exploited in the rectenna structure by inserting a MIM diode. In fact, a rectangular dielectric layer of Al_2O_3 with a permittivity equal to $\epsilon_r = 0.309 + j0.618$ at 28.3 THz, thickness 1.5 nm, and size $0.21 \mu\text{m}^2$ is placed above the center of the simulated nano-antenna. A rectangular gold conductive layer of length $d = 0.35 \mu\text{m}$, width $c = 0.2 \mu\text{m}$, and thickness $0.14 \mu\text{m}$ is inserted as shown in Fig. 5 (a).

Then, the designed double nano-antenna, composed of four Vivaldi arms forming an array of two dipoles, is used to create a nano-rectenna array. These two elements have been coupled in the form of an array by adding a single diode, as shown in Fig. 5 (b).

A. Nano-rectenna array design

The MIM diode is used for IR rectification with the optical nano-antenna. The diode incorporates an insulator layer between two electrodes, which are sufficiently thin to allow tunnel conduction. To integrate the MIM diode into the nanoarray of two Vivaldi antennas, we followed the same principle of the MIM rectifier, an insulator layer of dimension $0.2 \times 0.105 \mu\text{m}^2$ and of the same thickness, then a conductive layer of gold of dimension $0.2 \times 0.25 \mu\text{m}^2$ is inserted in the same area of the diode.

The Vivaldi planar nanoarray (2×3) designed to increase the electric field picked up for solar energy collection applications is shown in Fig. 5 (c). The far-field characteristics are improved by coupling numerous elements in the form of an array, and the output voltage is increased. The dimensions of the MIM diode are each time modified in order to reach a maximum value of the field at the frequency of the resonance. A single diode was used for the network of three elements. The insulating layer of Al_2O_3 of dimension $0.2 \times 0.215 \mu\text{m}^2$ was used in the simulation. We have selected the conductive layer of gold of dimension $0.2 \times 0.355 \mu\text{m}^2$ in our study. Four Vivaldi elements, coupled together in a single array with a common gap, is shown in Fig. 5 (d). All of the features in Fig. 5 (d) have the same dimensions as the Vivaldi nano-antenna, as depicted in Fig. 1. A single diode was used for the array of three elements.

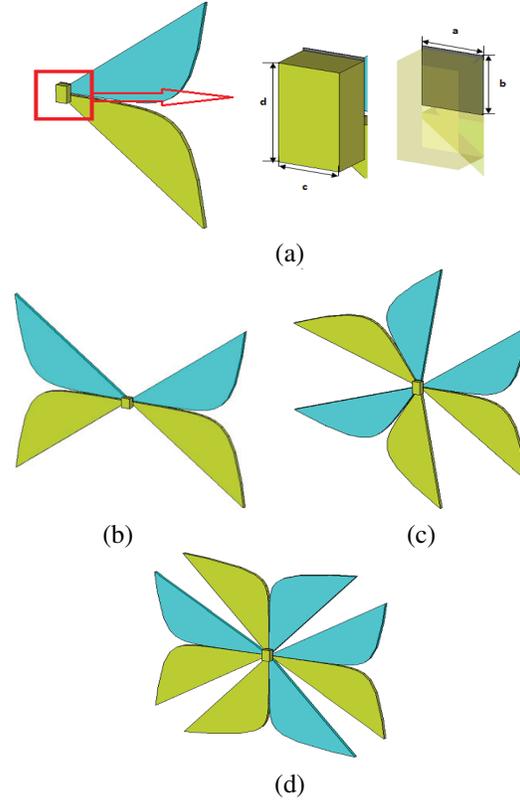


Fig. 5. Nano-rectenna configuration: (a) single array, (b) two elements, (c) three elements, and (d) four elements.

IV. DISCUSSION

The electric fields captured inside the common gap of the one, two, three, and four-element nanoarray are calculated and plotted versus frequency from 26 THz to 30 THz, as shown in Fig. 6.

The Vivaldi nano-antenna array resonates at 13 μm . Furthermore, it is clear that the Vivaldi network with

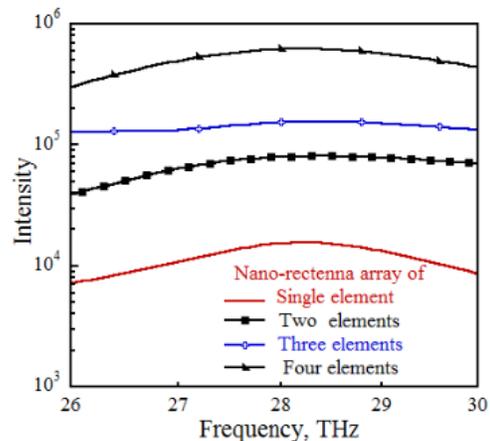


Fig. 6. The intensity variation vs. frequency for different studied nanoarrays.

four elements at the highest captured electric field, which is more than six times greater than that of the array with a single element. The intensity of the electric field increases by increasing the number of elements forming the nanoarray.

Thus, in this approach, the arrays designed have contributed to increasing the field of view at the level of the common gap when a single rectifier is necessary instead of two or more. This means that we have reduced the heat losses in the rectifiers and increased the total efficiency of the rectenna.

Table 2 summarizes the simulation results of the Vivaldi nano-rectennas designed. Vivaldi nano-rectennas resonate at 28.3 THz, and they always operate in the desired infrared band. Furthermore, it is clear that the Vivaldi array with four elements produces the highest captured electric field, which is more than double the highest value for the two-element array, and more than four times the highest value for the single Vivaldi element.

Table 2: Comparison between different Vivaldi nano-rectenna configurations

Array Element	E-max (V/m)	Intensity
One element	124	1.5×10^4
Two elements	284	8×10^4
Three elements	393	15.4×10^4
Four elements	790	62.4×10^4

V. CONCLUSION

A Vivaldi nano-antenna array for solar energy harvesting application at infrared frequencies 26-30 THz is designed and optimized. The first study is done to examine the captured field at the common gap for the single, double, three, and four nano-antenna with a resonant frequency of 28.3 THz. The second study is done by integrating a MIM diode into the designed arrays. The MIM diode is a very thin device made up of a very thin layer of Al_2O_3 sandwiched between two metal electrodes. It is noted that the resonant frequency for this array is 28.3 THz with a maximum electric field intensity of value 62.4×10^4 J for a nanoarray of four elements.

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